



60V DUAL N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	R _{DS(ON)}	I _D Tc = +25°C
60V	18mΩ @ V _{GS} = 10V	17.1A
	24.5mΩ @ V _{GS} = 4.5V	14.7A

Features

- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- Thermally Efficient Package-Cooler Running Applications
- High Conversion Efficiency
- Low R_{DS(ON)} Minimizes On State Losses
- Low Input Capacitance
- Fast Switching Speed
- Wettable Flank for Improved Optical Inspection
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Description and Applications

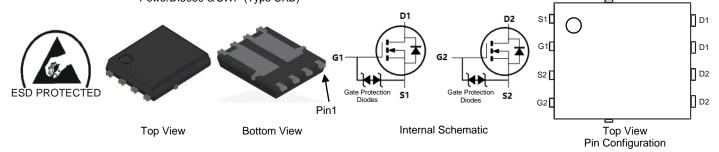
This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- Wireless Charging
- DC-DC Converters
- Power Management

PowerDI5060-8/SWP (Type UXD)

Mechanical Data

- Case: PowerDI[®]5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe;
 Solderable per MIL-STD-202, Method 208 (§3)
- Weight: 0.097 grams (Approximate)



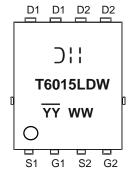
Ordering Information (Note 4)

Part Number	Case	Packaging
DMT6015LPDW-13	PowerDI5060-8/SWP (Type UXD)	2500/Tape & Reel

Notes: 1. No pu

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



☐ H = Manufacturer's Marking
☐ Marking Code
☐ Marking Code
☐ Marking
☐ Last Two Digits of Year (ex: 20 = 2020)
☐ WW = Week Code (01 to 53)



Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	VDSS	60	V	
Gate-Source Voltage		V_{GSS}	±16	V
Continuous Drain Current, Vgs = 10V (Note 6)	T _C = +25°C T _C = +70°C	lo	17.1 13.7	Α
Continuous Drain Current, $V_{GS} = 10V$ (Note 5) $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$		I _D	9.4 7.5	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	68	Α	
Maximum Continuous Body Diode Forward Current (Note 6)	Is	17	Α	
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)	Ism	68	Α	
Avalanche Current L = 0.1mH	las	20.7	Α	
Avalanche Energy L = 0.1mH	Eas	21.4	mJ	

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _A = +25°C	PD	2.4	W
Thermal Resistance, Junction to Ambient (Note 5)		Reja	52.1	°C/W
Total Power Dissipation (Note 6)	T _C = +25°C	P _D	7.9	W
Thermal Resistance, Junction to Case (Note 6)		Rejc	15.8	°C/W
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	60	_	_	V	$V_{GS} = 0V, I_{D} = 250\mu A$	
Zero Gate Voltage Drain Current	IDSS	_	_	1	μΑ	V _{DS} = 48V, V _{GS} = 0V	
Gate-Source Leakage	Igss	_	_	±10	μΑ	$V_{GS} = \pm 16V$, $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)			•		•	•	
Gate Threshold Voltage	V _{GS(TH)}	1.2	_	2.5	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
Static Drain-Source On-Resistance		_	13.7	18	mΩ	V _G S = 10V, I _D = 10A	
Static Drain-Source On-Resistance	Rds(on)	_	18.3	24.5	11177	V _G S = 4.5V, I _D = 6A	
Diode Forward Voltage	V_{SD}	_	0.7	1.2	V	V _G S = 0V, I _S = 1A	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss		808	_		V _{DS} = 30V, V _{GS} = 0V, f = 1MHz	
Output Capacitance	Coss		279	_	pF		
Reverse Transfer Capacitance	Crss	_	30	_			
Gate Resistance	Rg		1.4	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (VGS = 4.5V)	Qg	_	8.6	_			
Total Gate Charge (V _{GS} = 10V)	Qg	_	15.7	_	~_	201/ 1- 404	
Gate-Source Charge	Qgs		2.9	_	nC	$V_{DS} = 30V, I_{D} = 10A$	
Gate-Drain Charge	Q _{gd}		3.4	_			
Turn-On Delay Time	td(on)		7.5	_			
Turn-On Rise Time	tR	_	2.7	_		Vgs = 10V, Vps = 30V,	
Turn-Off Delay Time	t _{D(OFF)}		17.4	_	ns	$R_G = 6\Omega$, $I_D = 10A$	
Turn-Off Fall Time	tr		8.9	_			
Reverse Recovery Time	trr		26.7	_	ns	1 404 11/11 4004/	
Reverse Recovery Charge	Qrr	1	16.2	_	nC	I _F = 10A, di/dt = 100A/μs	

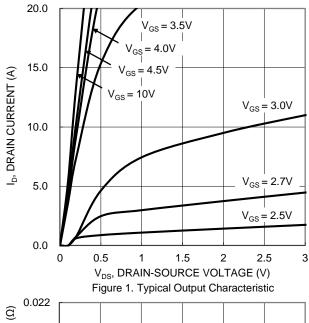
5. Device mounted on FR-4 substrate PC board, 2oz. copper, with thermal bias to bottom layer 1inch square copper plate.

^{6.} Thermal resistance from junction to soldering point (on the exposed drain pad).
7. Short duration pulse test used to minimize self-heating effect.

^{8.} Guaranteed by design. Not subject to product testing.







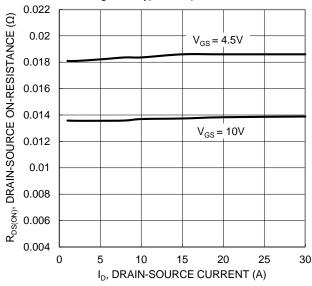


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

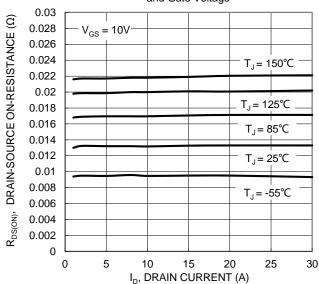
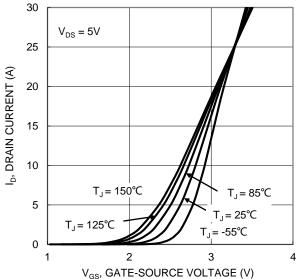


Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature



V_{GS}, GATE-SOURCE VOLTAGE (V)
Figure 2. Typical Transfer Characteristic

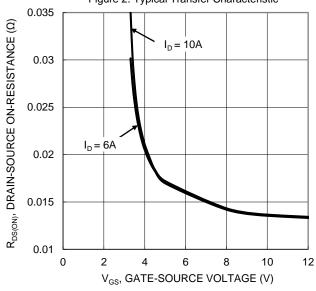
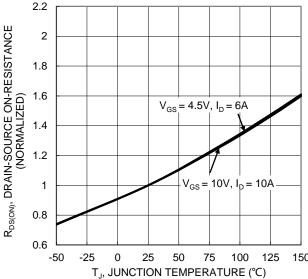


Figure 4. Typical Transfer Characteristic



T_J, JUNCTION TEMPERATURE (°C)
Figure 6. On-Resistance Variation with Junction
Temperature





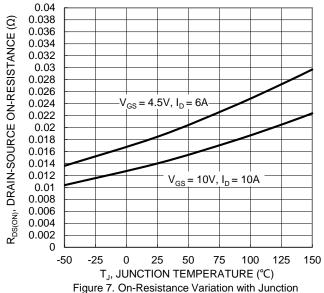


Figure 7. On-Resistance Variation with Junction Temperature

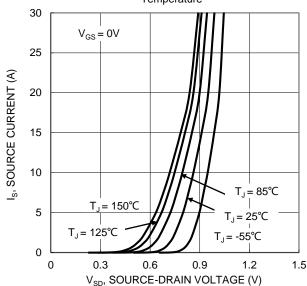


Figure 9. Diode Forward Voltage vs. Current

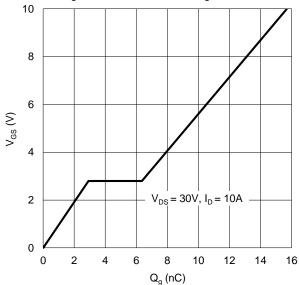


Figure 11. Gate Charge

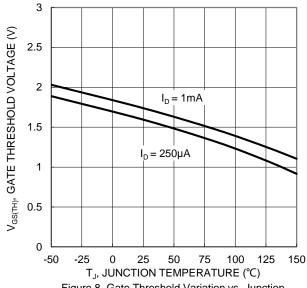
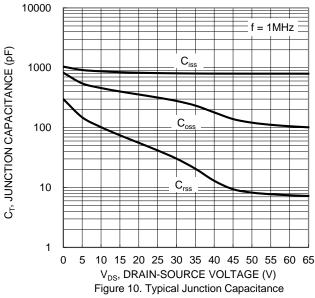


Figure 8. Gate Threshold Variation vs. Junction Temperature



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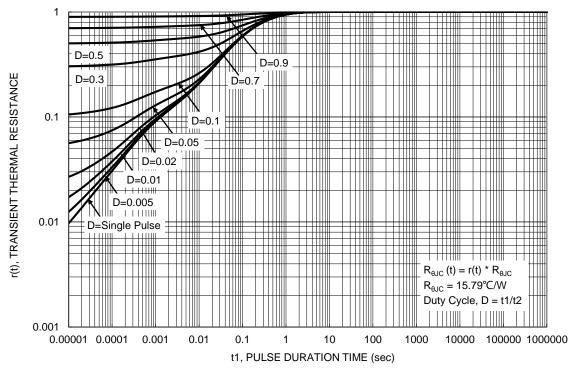


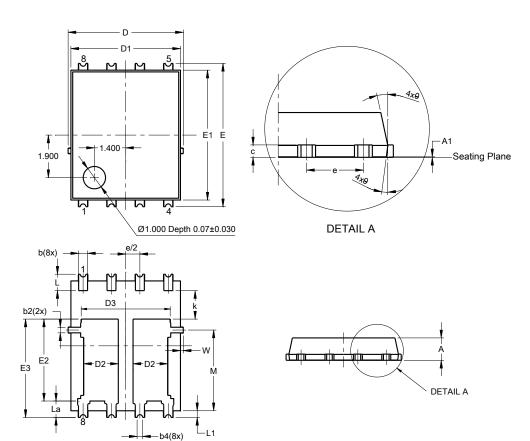
Figure 13. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8/SWP (Type UXD)

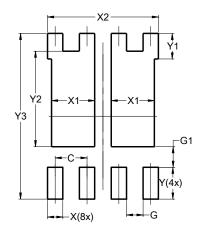


PowerDI5060-8/SWP					
(Type UXD)					
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0.00	0.05			
b	0.30	0.50	0.41		
b2	0.20	0.35	0.25		
b4).25REF	=		
C	0.230	0.330	0.277		
D	5	.15 BS0)		
D1	4.70	5.10	4.90		
D2	1.46	1.66	1.55		
D3	3.78	4.18	3.98		
Е	6	.40 BS0)		
E1	5.60	6.00	5.80		
E2	3.46	3.86	3.66		
E2a	4.195	4.595	4.395		
е	1.27BSC				
k	1.05				
L	0.635	0.835	0.735		
La	0.635	0.835	0.735		
L1	0.200	0.400	0.300		
М	3.205	4.005	3.605		
W	0.025	0.225	0.125		
θ	10°	12°	11°		
θ1	6°	8°	7°		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8/SWP (Type UXD)



Dimensions	Value		
פווטופוופוווט	(in mm)		
С	1.270		
G	0.660		
G1	0.820		
X	0.610		
X1	1.720		
X2	4.420		
Y	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



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